MOSFETs Silicon N-channel MOS (U-MOSVII-H)

TK100A10N1

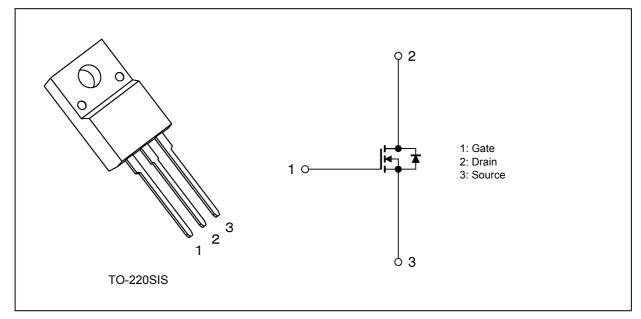
1. Applications

Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 3.1 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (2) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 100 \ V)$
- (3) Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_{D} = 1.0 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics				Rating	Unit
Drain-source voltage			V _{DSS}	100	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)	(Silicon limit)	(Note 1,2)	Ι _D	207	A
Drain current (DC)	(T _c = 25°C)	(Note 1)	I _D	100	
Drain current (pulsed)	(t = 1 ms)	(Note 1)	I _{DP}	362	
Power dissipation	(T _c = 25°C)		PD	45	W
Single-pulse avalanche energy		(Note 3)	E _{AS}	222	mJ
Avalanche current			I _{AR}	100	A
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	2.77	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	62.5	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Limited by silicon chip capability. Package limit is 100 A.

Note 3: V_DD = 80 V, T_ch = 25°C (initial), L = 17.1 μ H, R_G = 1.2 Ω , I_{AR} = 100 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

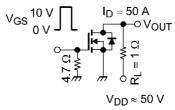
6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	—	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V	-	—	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	100		_	V
Drain-source breakdown voltage (Note 4)	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	65	_	_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1.0 mA	2.0	—	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 50 A	_	3.1	3.8	mΩ

Note 4: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz	_	8800	_	pF
Reverse transfer capacitance	C _{rss}			63	—	
Output capacitance	C _{oss}			1500	_	
Gate resistance	r _g	_	_	2.6	_	Ω
Switching time (rise time)	tr	See Figure 6.2.1	_	32	—	ns
Switching time (turn-on time)	t _{on}			59	_	
Switching time (fall time)	t _f]		45		
Switching time (turn-off time)	t _{off}		_	140	_	



Duty \leq 1%, t_w = 10 μ s

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 80 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 100 \text{ A}$		140	—	nC
Gate-source charge 1	Q _{gs1}		_	46	_	
Gate-drain charge	Q _{gd}		_	34	—	
Gate switch charge	Q_{SW}		_	55	_	

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 5)	I _{DR}	—	_	_	100	А
Reverse drain current (pulsed)	(Note 5)	I _{DRP}	—	_	—	362	
Diode forward voltage		V _{DSF}	I _{DR} = 100 A, V _{GS} = 0 V	—	—	-1.2	V
Reverse recovery time	(Note 6)	t _{rr}	I _{DR} = 100 A, V _{GS} = 0 V		93		ns
Reverse recovery charge	(Note 6)	Q _{rr}	-dI _{DR} /dt = 100 A/µs	_	220	_	nC

Note 5: Ensure that the channel temperature does not exceed 150°C. Note 6: Ensure that V_{DS} peak does not exceed V_{DSS} .

7. Marking (Note)

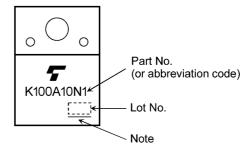


Fig. 7.1 Marking

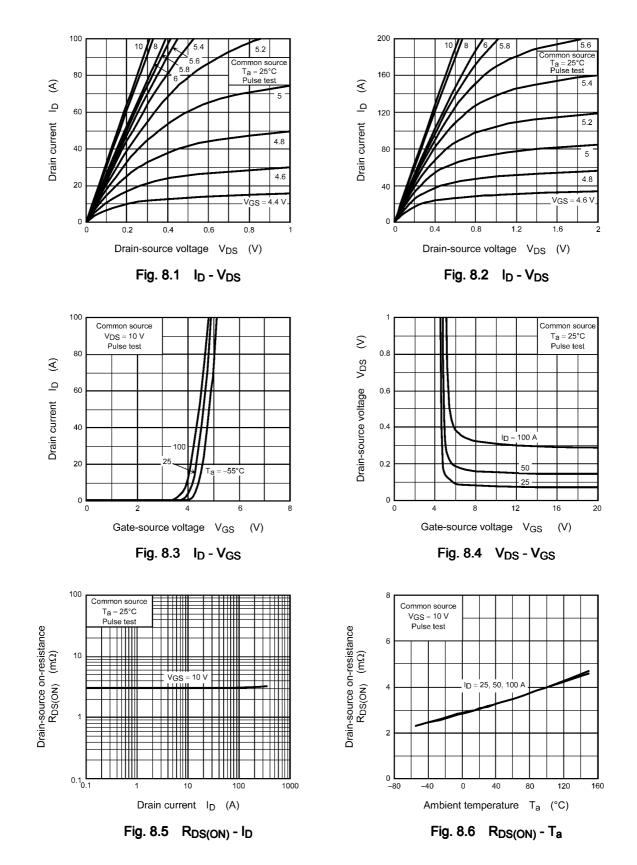
Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

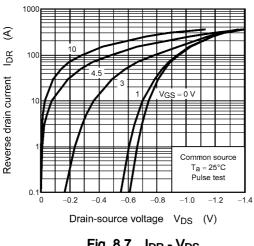
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

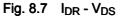
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

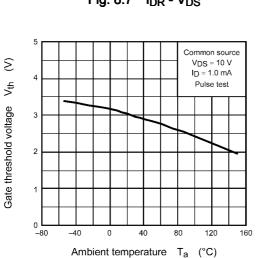
The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

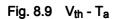
8. Characteristics Curves (Note)

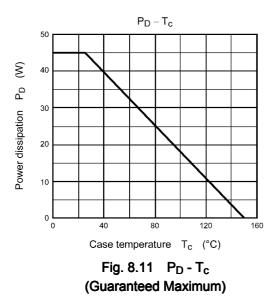












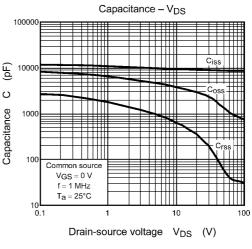


Fig. 8.8 Capacitance - V_{DS}

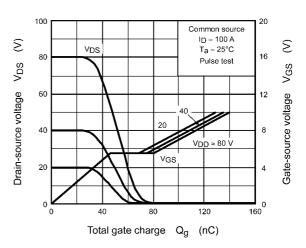
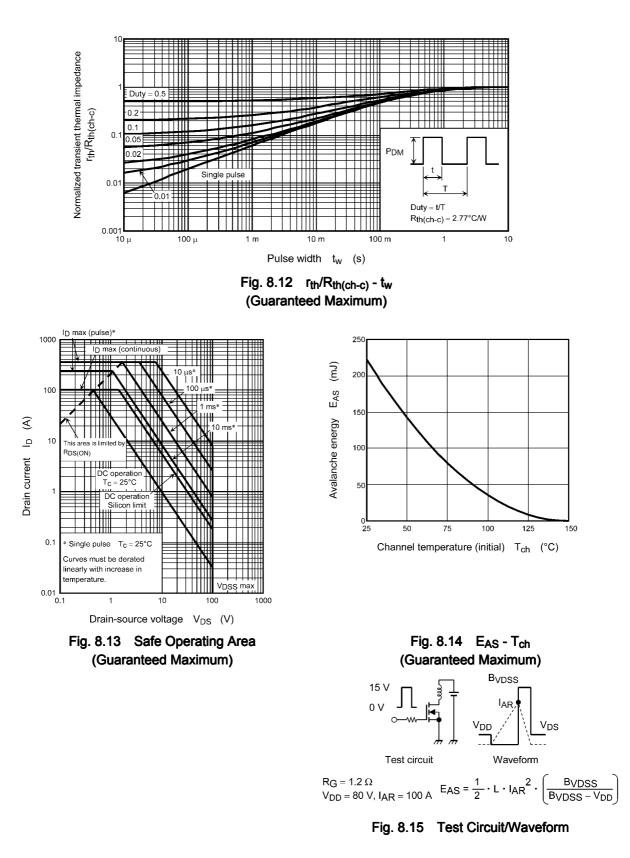


Fig. 8.10 Dynamic Input/Output Characteristics



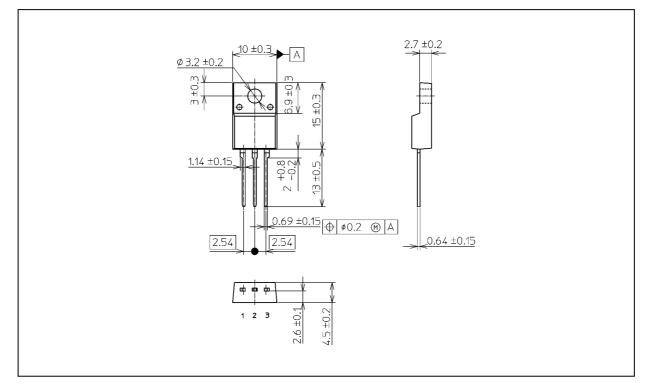


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

TK100A10N1

Package Dimensions

Unit: mm



Weight: 1.7 g (typ.)

Package Name(s)				
JEITA: SC-67				
TOSHIBA: 2-10U1S				
Nickname: TO-220SIS				

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